TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74LCX05F,TC74LCX05FN,TC74LCX05FT,TC74LCX05FK

Low-Voltage HEX Inverter with 5-V Tolerant Inputs and Outputs (open-drain)

The TC74LCX05 is a high-performance CMOS inverter. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

Pin configuration and function are the same as the TC74LCX04, but the TC74LCX05F/FN/FT has high performance MOS N-channel transistor. (open-drain outputs)

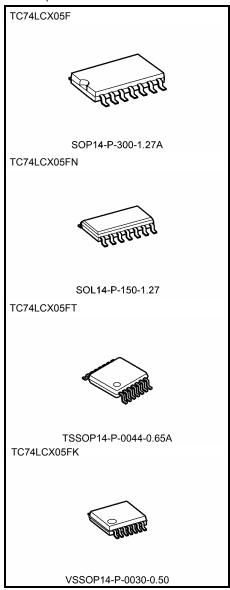
The device is designed for low-voltage (3.3 V)  $V_{\rm CC}$  applications, but it could be used to interface to 5-V supply environment for inputs.

All inputs are equipped with protection circuits against static discharge.

#### **Features**

- Low-voltage operation: V<sub>CC</sub> = 2.0 to 3.6 V
- High-speed operation:  $t_{pz} = 5.0 \text{ ns (max) (V}_{CC} = 3.0 \text{ to } 3.6 \text{ V})$
- Output current: IOL = 24 mA (min) (VCC = 3.0 V)
- Latch-up performance: -500 mA
- Available in JEDEC SOP, JEITA SOP, TSSOP and VSSOP (US)
- Open-drain outputs
- Power-down protection is provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 05 type

Note: xxxFN (JEDEC SOP) is not available in Japan.



Weight

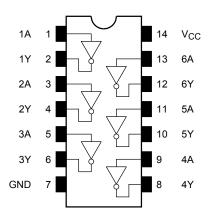
 SOP14-P-300-1.27A
 : 0.18 g (typ.)

 SOL14-P-150-1.27
 : 0.12 g (typ.)

 TSSOP14-P-0044-0.65A
 : 0.06 g (typ.)

 VSSOP14-P-0030-0.50
 : 0.02 g (typ.)

### Pin Assignment (top view)



#### **IEC Logic Symbol**

1	1	4 ^		2	- 1Y
1A -	3	1 ⊻	$-\!\Gamma$	4	
2A -	5			6	2Y
3A -	9		_	8	3Y
4A -	11		_	10	4Y
5A -	13		_	12	5Y
6A -	13			12	6Y

#### **Truth Table**

Inputs	Outputs
Α	Y
L	Z
Н	L

Z: High impedance

#### System Diagram (per gate)

$$\mathsf{A} \xrightarrow{\hspace*{1cm}} \mathsf{V} \xrightarrow{\hspace*{1cm}} \mathsf{V}$$

#### **Absolute Maximum Ratings (Note 1)**

Characteristics	Symbol	Rating	Unit
Power supply voltage	V <sub>CC</sub>	−0.5 to 7.0	V
DC input voltage	V <sub>IN</sub>	−0.5 to 7.0	٧
		-0.5 to 7.0 (Note 2)	V
DC output voltage	Vout	-0.5 to V <sub>CC</sub> + 0.5 (Note 3)	
Input diode current	lıK	-50	mA
Output diode current	lok	−50 (Note 4)	mA
DC output current	lout	50	mA
Power dissipation	PD	180	mW
DC V <sub>CC</sub> /ground current	I <sub>CC</sub> /I <sub>GND</sub>	±100	mA
Storage temperature	T <sub>stg</sub>	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

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Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: Output in OFF state

Note 3: Low state. IOUT absolute maximum rating must be observed.

Note 4: VOUT < GND



## **Operating Ranges (Note 1)**

Characteristics	Symbol Rating		Unit	
Power supply voltage	V <sub>CC</sub>	2.0 to 3.6	V	
Tower supply voltage	vcc vcc	1.5 to 3.6 (Note 2)	V	
Input voltage	V <sub>IN</sub>	0 to 5.5	V	
Output voltage	\/a=	0 to 5.5 (Note 3)	V	
Output voltage	Vout	0 to V <sub>CC</sub> (Note 4)	V	
Output current	lou	24 (Note 5)	mA	
Output current	loL	12 (Note 6)	IIIA	
Operating temperature	T <sub>opr</sub>	-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 10 (Note 7)	ns/V	

Note 1: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

Note 2: Data retention only

Note 3: Output in OFF state

Note 4: Low state

Note 5:  $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$ 

Note 6:  $V_{CC} = 2.7 \text{ to } 3.0 \text{ V}$ 

Note 7:  $V_{IN} = 0.8$  to 2.0 V,  $V_{CC} = 3.0$  V

#### **Electrical Characteristics**

### DC Characteristics ( $Ta = -40 \text{ to } 85^{\circ}\text{C}$ )

Characteristics		Symbol	Test Condition		V <sub>CC</sub> (	Min	Max	Unit
	H-level	V <sub>IH</sub>	_		2.7 to	3.6 2.0	_	V
Input voltage	L-level	V <sub>IL</sub>		_	2.7 to	3.6 —	0.8	V
			V <sub>OL</sub> V <sub>IN</sub> = V <sub>IH</sub>	I <sub>OL</sub> = 100 μ	A 2.7 to	3.6 —	0.2	V
Output valtage	L-level	V		I <sub>OL</sub> = 12 m/	A 2.7	_	0.4	
Output voltage	L-level	VOL		I <sub>OL</sub> = 16 m/	A 3.0	_	0.4	
				I <sub>OL</sub> = 24 m/	A 3.0	_	0.55	
Input leakage current		I <sub>IN</sub>	V <sub>IN</sub> = 0 to 5.5 V	•	2.7 to	3.6 —	±5.0	μА
Output OFF state	Output OFF state current		$V_{IN} = V_{IL}$ , $V_{OUT} = 0$ to 5.5 V		2.7 to	3.6 —	±5.0	μΑ
Power-off leakage current		l <sub>OFF</sub>	V <sub>IN</sub> /V <sub>OUT</sub> = 5.5 V		0	_	10.0	μА
Quiescent supply current		l	V <sub>IN</sub> = V <sub>CC</sub> or GND		2.7 to	3.6 —	10.0	
		Icc	V <sub>IN</sub> /V <sub>OUT</sub> = 3.6 to 5.5 V		2.7 to	3.6 —	±10.0	μА
Increase in Icc per input		Δl <sub>CC</sub>	V <sub>IH</sub> = V <sub>CC</sub> - 0.6 V		2.7 to	3.6 —	500	



#### AC Characteristics ( $Ta = -40 \text{ to } 85^{\circ}\text{C}$ )

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
Output enable time	t <sub>pZL</sub>	Figure 1, Figure 2	2.7	1.0	6.0	ns
Cutput chable time			$3.3 \pm 0.3$	8.0	5.0	
Output disable time	t <sub>pLZ</sub>	Figure 1, Figure 2	2.7	1.0	6.0	ne
Output disable time			$3.3 \pm 0.3$	8.0	5.0	ns
Output to output skow	t <sub>osZL</sub>	(Note)	2.7			ne
Output to output skew			$3.3 \pm 0.3$		1.0	ns

Note: Para

Parameter guaranteed by design.

 $(t_{OSZL} = |t_{pZLm} - t_{pZLn}|)$ 

#### Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.5$ ns, $C_L = 50$ pF, $R_L = 500$ $\Omega$ )

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Unit
Quiet output maximum dynamic V <sub>OL</sub>	VOLP	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	8.0	V
Quiet output minimum dynamic V <sub>OL</sub>	V <sub>OLV</sub>	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V

## Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Unit
Input capacitance	C <sub>IN</sub>		3.3	7	pF
Output capacitance	C <sub>OUT</sub>	_	3.3	8	pF
Power dissipation capacitance	C <sub>PD</sub>	$f_{IN} = 10 \text{ MHz}$ (Not	9) 3.3	5	pF

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Note:

 $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC}$  (opr) =  $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6$  (per gate)

### **AC Test Circuit**

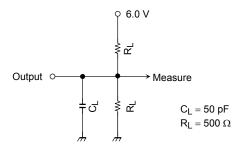


Figure 1

#### **AC Waveform**

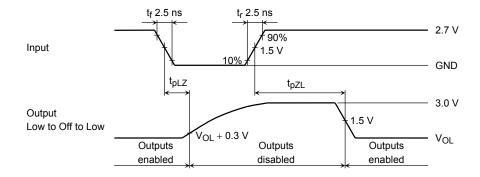
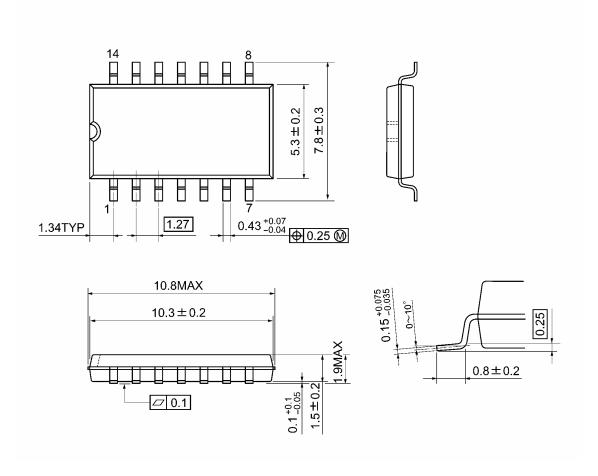


Figure 2  $t_{pLZ}$ ,  $t_{pZL}$ 

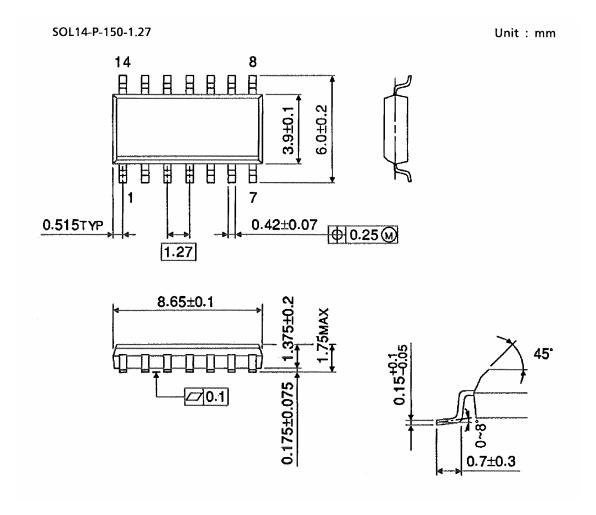
# **Package Dimensions**

SOP14-P-300-1.27A Unit: mm



Weight: 0.18 g (typ.)

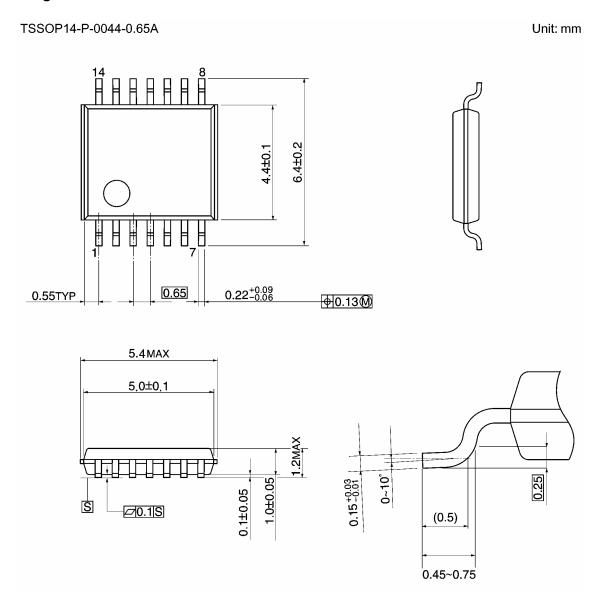
## **Package Dimensions (Note)**



Note: This package is not available in japan.

Weight: 0.12 g (typ.)

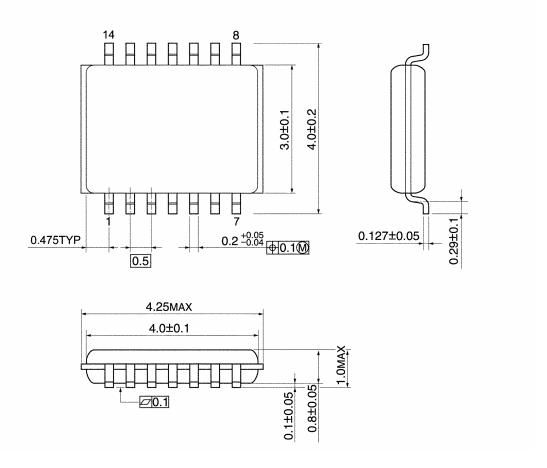
# **Package Dimensions**



Weight: 0.06 g (typ.)

# **Package Dimensions**

VSSOP14-P-0030-0.50 Unit: mm



Weight: 0.02 g (typ.)

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20070701-EN GENERAL

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